

### A2.7 (D. Schaad)

- [A2.7:1] \* P.R. Ganz, C. Sürgers, G. Fischer, and D.M. Schaad, *Cu-doped GaN grown by molecular beam epitaxy*, J. Phys. Conf. Series **200**, 062006 (2010)
- [A2.7:2] \*‡ R. Schuber, M.M.C. Chou, P. Vincze, Th. Schimmel, and D.M. Schaad, *Growth of A-plane GaN growth on LiGaO<sub>2</sub>(010) by plasma-assisted molecular beam epitaxy*, J. Crystal Growth **312**, 1665 (2010)
- [A2.7:3] ‡ R. Schuber, M.M.C. Chou, and D.M. Schaad, *Growth of M-plane GaN on LiGaO<sub>2</sub>(100) by plasma-assisted molecular beam epitaxy*, Thin Solid Films **518**, 6773 (2010)
- [A2.7:4] \* P.R. Ganz, G. Fischer, C. Sürgers, and D.M. Schaad, *Cu-doped nitrides: promising candidates for a nitride based spinaligner*, J. Crystal Growth **323**, 355 (2011)
- [A2.7:5] \*‡ R. Schuber, Y.L. Chen, C.H. Shih, T.H. Huang, P. Vincze, I. Lo, L.W. Chang, Th. Schimmel, M.M.C. Chou, and D.M. Schaad, *Growth of non-polar GaN on LiGaO<sub>2</sub> by plasma-assisted MBE*, J. Crystal Growth **323**, 76 (2011)
- [A2.7:6] \*‡ T.-H. Huang, P.R. Ganz, L. Chang, and D.M. Schaad, *Formation Mechanisms of Islands on Cu-Alloyed GaN Grown by Plasma Assisted Molecular Beam Epitaxy*, J. Electrochem. Soc. **158**, H860 (2011)
- [A2.7:7] \*‡ C.-H. Shih, T.-H. Huang, R. Schuber, Y.-L. Chen, L. Chang, I. Lo, M.M.C. Chou, and D.M. Schaad, *Microstructure of non-polar GaN on LiGaO<sub>2</sub> grown by plasma-assisted MBE*, Nanoscale Res. Lett. **6**, 425 (2011)